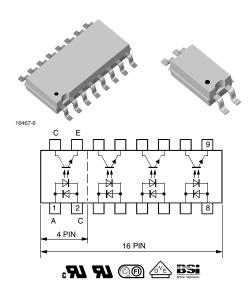


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Optocoupler, Phototransistor Output, AC Input, Single/Quad Channel, Half Pitch Mini-Flat Package



DESCRIPTION

The low profile miniflat package includes an optocoupler with AC Input and transistor output. It is available in single channel (4 pin) TCMT1600 or quad channel (16 pin) TCMT4600.

FEATURES

- Low profile package (half pitch)
- AC isolation test voltage 3750 V_{RMS}
- Low coupling capacitance of typical 0.3 pF
- · Low temperature coefficient of CTR
- · Wide ambient temperature range
- Compliant to RoHS Directive 2002/95/EC accordance to WEEE 2002/96/EC





and in

APPLICATIONS

• Programmable logic controllers

AGENCY APPROVALS

- UL1577, file no. E76222 system code M, double protection
- cUL CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDA 0884)
 DIN EN 60747-5-5 (pending)
- FIMKO: FI EN 60950-1:2006
- BSI: BS EN60065:2002
 BS EN60950-1:2006

ORDERING INFORMATION								
T C M	T # 6	6 0 #	SOP-#					
AGENCY CERTIFIED/PACKAGE	CTR (%)							
AGENCY CENTIFIED/PACKAGE	SINGLE CHANNEL	QUAD C	HANNEL					
UL, cUL, FIMKO, BSI, VDE 80 to 300 80 to 300			100 to 300					
SOP-4	TCMT1600	-	-					
SOP-4	TCMT1600T3 (1)	-	-					
SOP-16	-	TCMT4600	TCMT4606					
SOP-16 -		TCMT4600T0 (1)	-					

Notes

- Available only on tape and reel.
- (1) Product is rotated 180° in tape and reel cavity.

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE UNIT					
INPUT								
Forward current		I _F	± 60	mA				
Forward surge current	t _p ≤ 10 μs	I _{FSM}	± 1.5	А				
Power dissipation		P _{diss}	100	mW				
Junction temperature		Tj	125	°C				

TCMT1600, TCMT4600 Series

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
OUTPUT							
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	Ісм	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		T _j	125	°C			
COUPLER							
AC isolation test voltage (RMS)		V _{ISO}	3750	V_{RMS}			
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 125	°C			
Soldering temperature (1)		T _{sld}	260	°C			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (2) Wave soldering three cycles are allowed. Also refer to "Assembly Instructions" (www.vishay.com/doc?80054).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	$I_F = \pm 50 \text{ mA}$	V _F		1.25	1.6	V		
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j		50		pF		
OUTPUT	OUTPUT							
Collector emitter voltage	I _C = 100 μA	V_{CEO}	70			V		
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V		
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0$	I _{CEO}			100	nA		
COUPLER								
Collector emitter saturation voltage	$I_F = \pm 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}			0.3	V		
Cut-off frequency	V_{CE} = 5 V, I_F = ± 10 mA, R_L = 100 Ω	f _c		100		kHz		
Capacitance (input to output)	f = 1 MHz	C _{IO}		0.3		pF		

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	IMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX. U						
I _C /I _F	V _{CE} = 5 V, I _F = ± 5 mA	TCMT1600	CTR	80		300	%
		TCMT4600	CTR	80		300	%
		TCMT4606	CTR	100		300	%



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SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _d		3		μs
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _r		3		μs
Fall time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _f		4.7		μs
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _s		0.3		μs
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _{on}		6		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _{off}		5		μs
Turn-on time	$V_S = 5$ V, $I_F = \pm 10$ mA, $R_L = 1$ k Ω (see figure 2)	t _{on}		9		μs
Turn-off time	$V_S = 5 \text{ V}, I_F = \pm 10 \text{ mA}, R_L = 1 \text{ k}\Omega$ (see figure 2)	t _{off}		18		μs

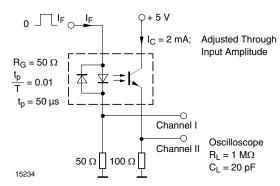


Fig. 1 - Test Circuit, Non-Saturated Operation

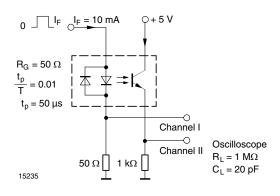


Fig. 2 - Test Circuit, Saturated Operation

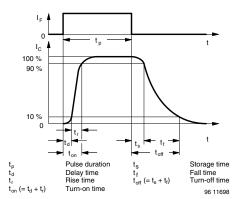


Fig. 3 - Switching Times

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

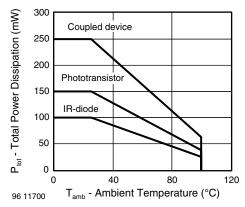
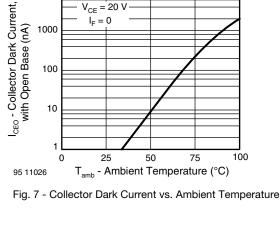


Fig. 4 - Total Power Dissipation vs. Ambient Temperature



V_{CE} = 20

10 000

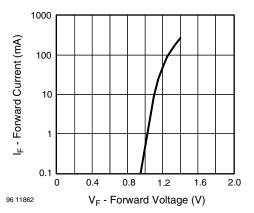


Fig. 5 - Forward Current vs. Forward Voltage

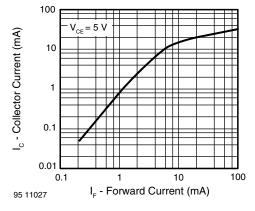


Fig. 8 - Collector Current vs. Forward Current

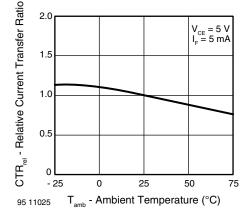


Fig. 6 - Relative Current Transfer Ratio vs. **Ambient Temperature**

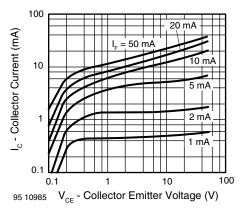


Fig. 9 - Collector Current vs. Collector Emitter Voltage

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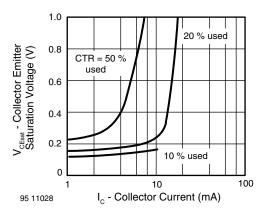


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

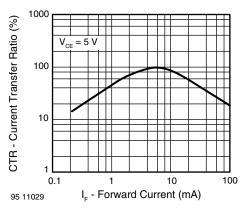


Fig. 11 - Current Transfer Ratio vs. Forward Current

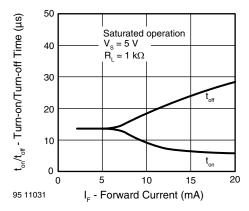


Fig. 12 - Turn-on/Turn-off Time vs. Forward Current

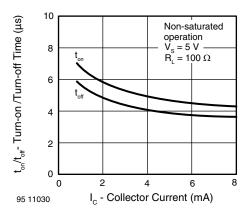
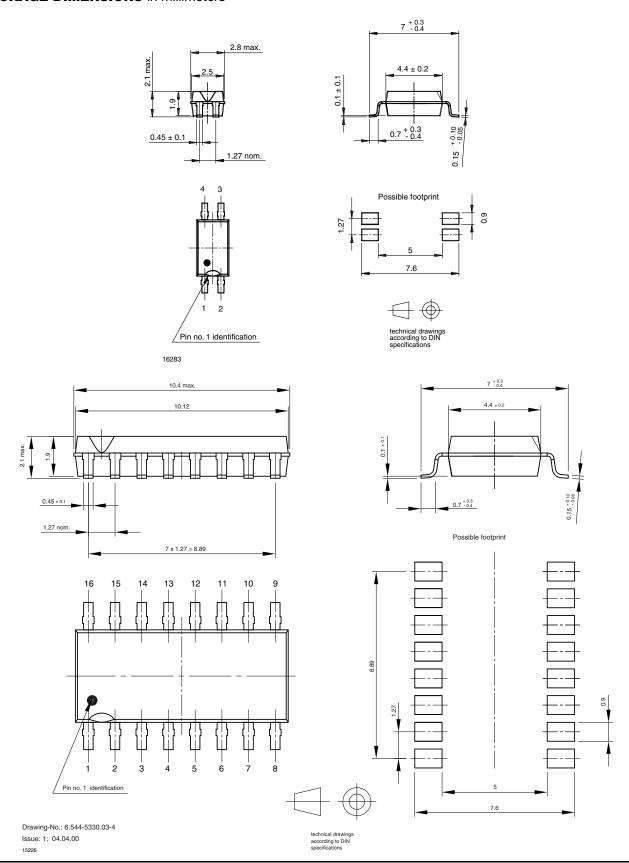


Fig. 13 - Turn-on/Turn-off Time vs. Collector Current

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PACKAGE DIMENSIONS in millimeters





TCMT1600, TCMT4600 Series

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PACKAGE MARKING

O MT1600 V YWW M 68 TCMT4600

o VYWWM68



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